



BTA16, BTB16 and T16 Series

SNUBBERLESSTM, LOGIC LEVEL & STANDARD

16A TRIACs

Table 1: Main Features

Symbol	Value	Unit
$I_{T(RMS)}$	16	A
V_{DRM}/V_{RRM}	600, 700 and 800	V
$I_{GT}(Q_1)$	10 to 50	mA

DESCRIPTION

Available either in through-hole or surface-mount packages, the **BTA16**, **BTB16** and **T16** triac series is suitable for general purpose AC switching. They can be used as an ON/OFF function in applications such as static relays, heating regulation, induction motor starting circuits... or for phase control operation in light dimmers, motor speed controllers, ...

The snubberless versions (BTA/BTB...W and T16 series) are specially recommended for use on inductive loads, thanks to their high commutation performances. By using an internal ceramic pad, the BTA series provides voltage insulated tab (rated at $2500V_{RMS}$) complying with UL standards (File ref.: E81734).

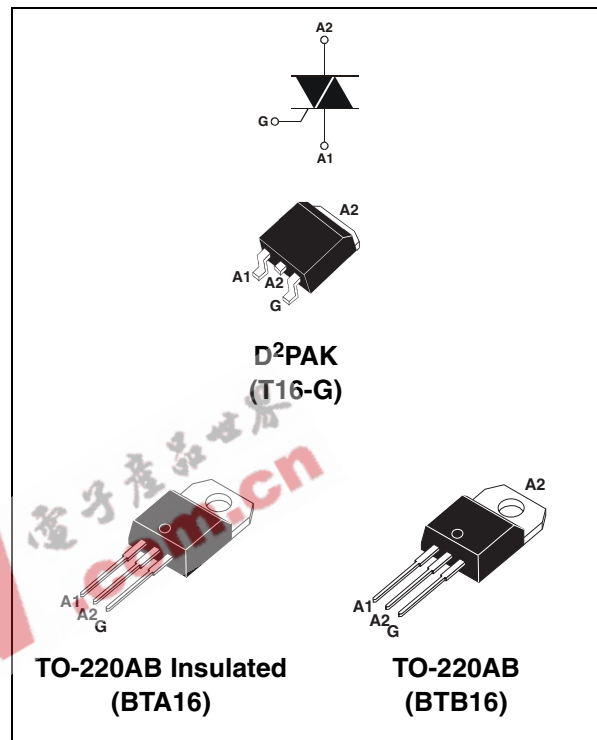


Table 2: Order Codes

Part Number	Marking
BTA16-xxxxxRG	See page table 8 on page 8
BTB16-xxxxxRG	
T16xx-xxxG	

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Table 3: Absolute Maximum Ratings

Symbol	Parameter			Value	Unit
$I_{T(RMS)}$	RMS on-state current (full sine wave)	D ² PAK / TO-220AB	$T_c = 100^\circ\text{C}$	16	A
		TO-220AB Ins.	$T_c = 15^\circ\text{C}$		
I_{TSM}	Non repetitive surge peak on-state current (full cycle, T_j initial = 25°C)	F = 50 Hz	t = 20 ms	160	A
		F = 60 Hz	t = 16.7 ms	168	
I^2t	I^2t Value for fusing	$t_p = 10$ ms		144	A ² s
dI/dt	Critical rate of rise of on-state current $I_G = 2 \times I_{GT}$, $t_r \leq 100$ ns	F = 120 Hz	$T_j = 125^\circ\text{C}$	50	A/ μs
V_{DSM}/V_{RSM}	Non repetitive surge peak off-state voltage	$t_p = 10$ ms	$T_j = 25^\circ\text{C}$	$V_{DSM}/V_{RSM} + 100$	V
I_{GM}	Peak gate current	$t_p = 20$ μs	$T_j = 125^\circ\text{C}$	4	A
$P_{G(AV)}$	Average gate power dissipation		$T_j = 125^\circ\text{C}$	1	W
T_{stg} T_j	Storage junction temperature range Operating junction temperature range			- 40 to + 150 - 40 to + 125	$^\circ\text{C}$

Tables 4: Electrical Characteristics ($T_j = 25^\circ\text{C}$, unless otherwise specified)

■ **SNUBBERLESS and Logic Level (3 quadrants)**

Symbol	Test Conditions	Quadrant		T16	BTA16 / BTB16			Unit
				T1635	SW	CW	BW	
I_{GT} (1)	$V_D = 12$ V $R_L = 33$ Ω	I - II - III	MAX.	35	10	35	50	mA
V_{GT}		I - II - III	MAX.	1.3				V
V_{GD}	$V_D = V_{DRM}$ $R_L = 3.3$ k Ω $T_j = 125^\circ\text{C}$	I - II - III	MIN.	0.2				V
I_H (2)	$I_T = 500$ mA		MAX.	35	15	35	50	mA
I_L	$I_G = 1.2$ I_{GT}	I - III	MAX.	50	25	50	70	mA
		II		60	30	60	80	
dV/dt (2)	$V_D = 67\%$ V_{DRM} gate open	$T_j = 125^\circ\text{C}$	MIN.	500	40	500	1000	V/ μs
(dI/dt)c (2)	(dV/dt)c = 0.1 V/ μs	$T_j = 125^\circ\text{C}$	MIN.	-	8.5	-	-	A/ms
	(dV/dt)c = 10 V/ μs	$T_j = 125^\circ\text{C}$		-	3.0	-	-	
	Without snubber	$T_j = 125^\circ\text{C}$		8.5	-	8.5	14	

■ Standard (4 quadrants)

Symbol	Test Conditions	Quadrant		BTA16 / BTB16		Unit
				C	B	
I_{GT} (1)	$V_D = 12\text{ V}$ $R_L = 33\ \Omega$	I - II - III IV	MAX.	25 50	50 100	mA
V_{GT}		ALL	MAX.	1.3		V
V_{GD}	$V_D = V_{DRM}$ $R_L = 3.3\text{ k}\Omega$ $T_j = 125^\circ\text{C}$	ALL	MIN.	0.2		V
I_H (2)	$I_T = 500\text{ mA}$		MAX.	25	50	mA
I_L	$I_G = 1.2 I_{GT}$	I - III - IV	MAX.	40	60	mA
		II		80	120	
dV/dt (2)	$V_D = 67\% V_{DRM}$ gate open	$T_j = 125^\circ\text{C}$	MIN.	200	400	V/ μs
$(dV/dt)_c$ (2)	$(dI/dt)_c = 7\text{ A/ms}$	$T_j = 125^\circ\text{C}$	MIN.	5	10	V/ μs

Table 5: Static Characteristics

Symbol	Test Conditions			Value	Unit	
V_T (2)	$I_{TM} = 22.5\text{ A}$	$t_p = 380\ \mu\text{s}$	$T_j = 25^\circ\text{C}$	MAX.	1.55	V
V_{to} (2)	Threshold voltage		$T_j = 125^\circ\text{C}$	MAX.	0.85	V
R_d (2)	Dynamic resistance		$T_j = 125^\circ\text{C}$	MAX.	25	m Ω
I_{DRM} I_{RRM}	$V_{DRM} = V_{RRM}$		$T_j = 25^\circ\text{C}$	MAX.	5	μA
			$T_j = 125^\circ\text{C}$		2	mA

Note 1: minimum I_{GT} is guaranteed at 5% of I_{GT} max.

Note 2: for both polarities of A2 referenced to A1.

Table 6: Thermal resistance

Symbol	Parameter		Value	Unit	
$R_{th(j-c)}$	Junction to case (AC)		D ² PAK / TO-220AB	1.2	$^\circ\text{C/W}$
			TO-220AB Insulated	2.1	
$R_{th(j-a)}$	Junction to ambient	S = 1 cm ²	D ² PAK	45	$^\circ\text{C/W}$
			TO-220AB / TO-220AB Insulated	60	

S = Copper surface under tab.

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Figure 1: Maximum power dissipation versus RMS on-state current (full cycle)

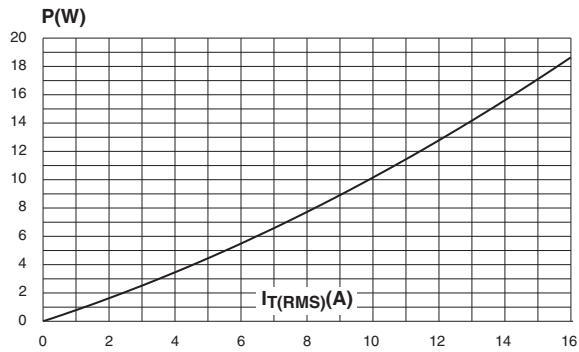


Figure 2: RMS on-state current versus case temperature (full cycle)

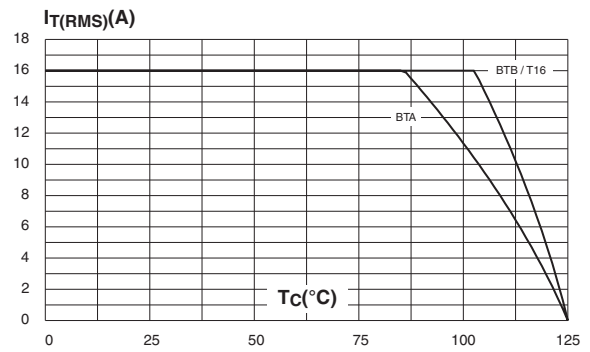


Figure 3: RMS on-state current versus ambient temperature (printed circuit board FR4, copper thickness: 35µm) (full cycle)

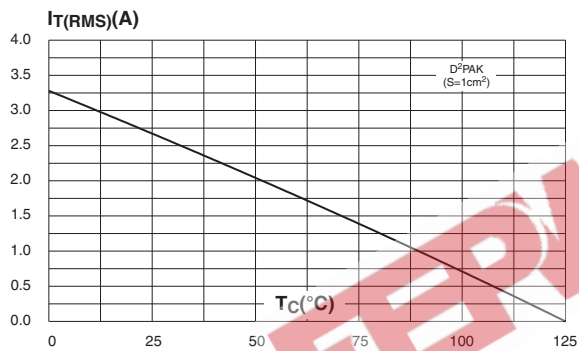


Figure 4: Relative variation of thermal impedance versus pulse duration

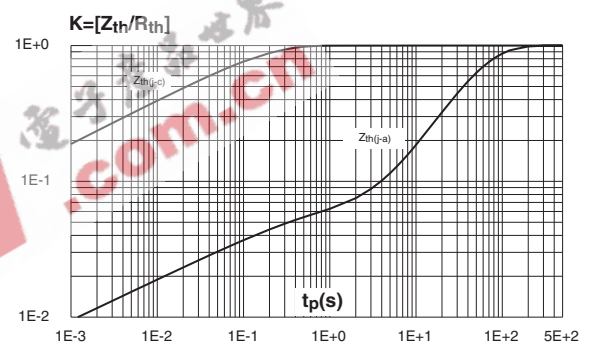


Figure 5: On-state characteristics (maximum values)

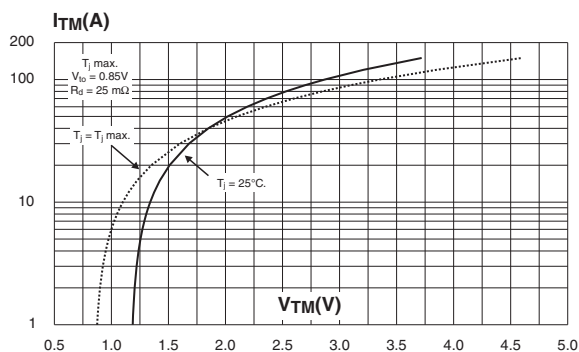


Figure 6: Surge peak on-state current versus number of cycles

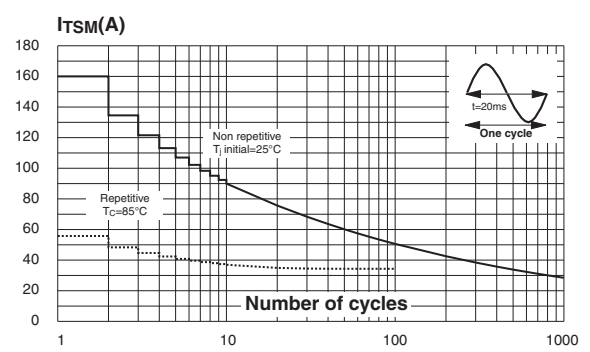


Figure 7: Non-repetitive surge peak on-state current for a sinusoidal pulse with width $t_p < 10$ ms and corresponding value of I^2t

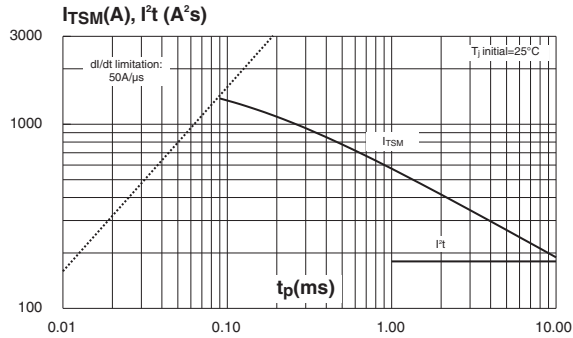


Figure 8: Relative variation of gate trigger current, holding current and latching current versus junction temperature (typical values)

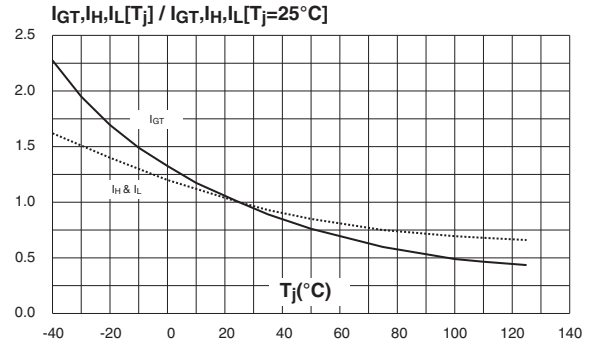


Figure 9: Relative variation of critical rate of decrease of main current versus $(dV/dt)_c$ (typical values) (Snubberless & Logic level types)

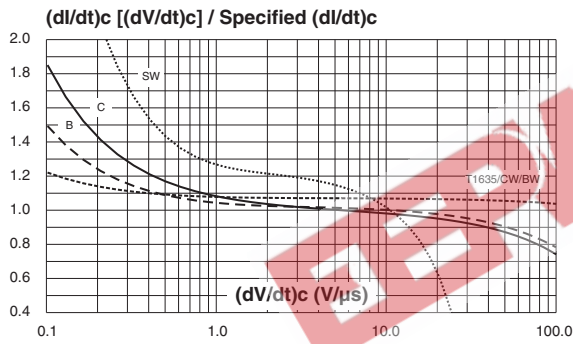


Figure 10: Relative variation of critical rate of decrease of main current versus $(dV/dt)_c$ (typical values) (Standard types)

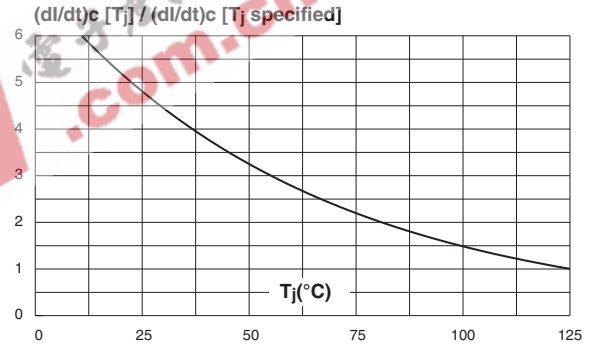
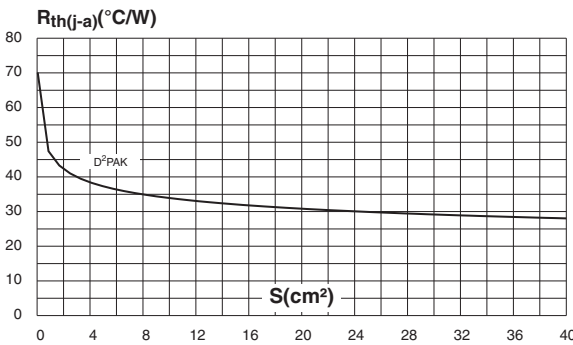


Figure 11: D²PAK Thermal resistance junction to ambient versus copper surface under tab (printed circuit board FR4, copper thickness: 35 μ m)



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Figure 12: Ordering Information Scheme (BTA16 and BTB16 series)

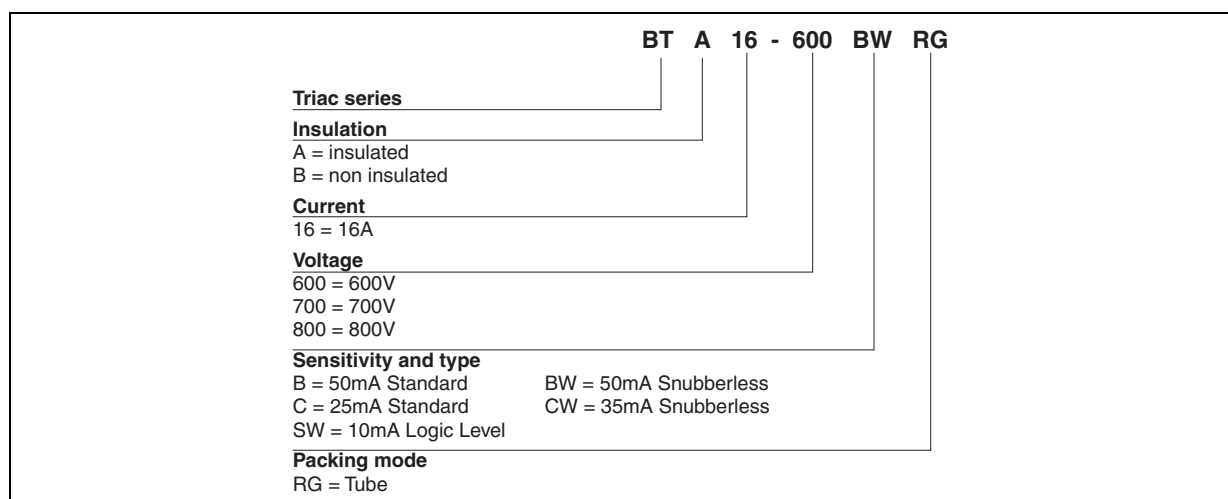


Figure 13: Ordering Information Scheme (T16 series)

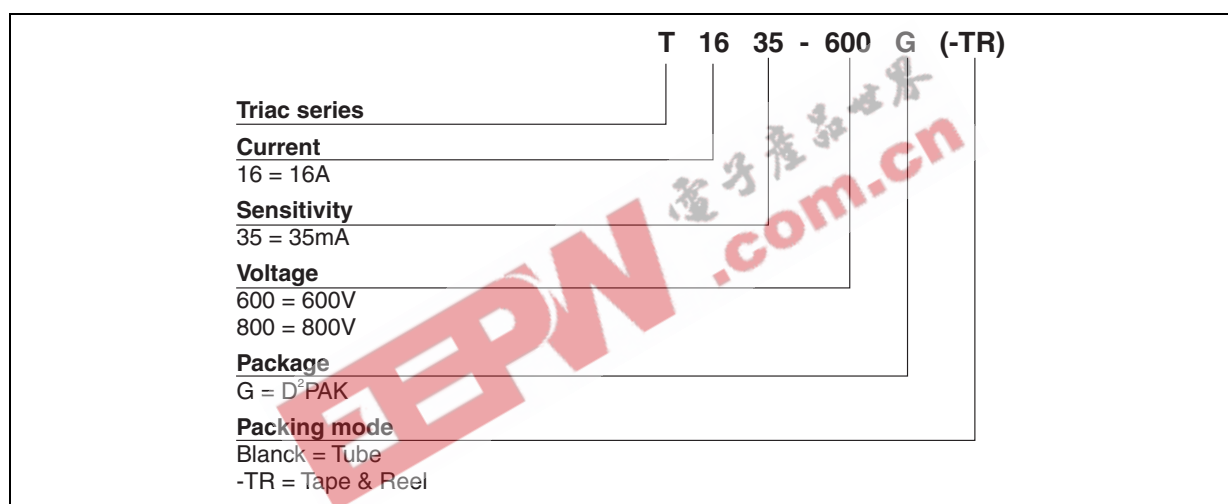


Table 7: Product Selector

Part Numbers	Voltage (xxx)			Sensitivity	Type	Package
	600 V	700 V	800 V			
BTA/BTB16-xxxB	X	X	X	50 mA	Standard	TO-220AB
BTA/BTB16-xxxBW	X	X	X	50 mA	Snubberless	TO-220AB
BTA/BTB16-xxxC	X	X	X	25 mA	Standard	TO-220AB
BTA/BTB16-xxxCW	X	X	X	35 mA	Snubberless	TO-220AB
BTA/BTB16-xxxSW	X	X	X	10 mA	Logic level	TO-220AB
T1635-xxxG	X		X	35 mA	Snubberless	D ² PAK

BTB: non insulated TO-220AB package

Figure 14: D²PAK Package Mechanical Data

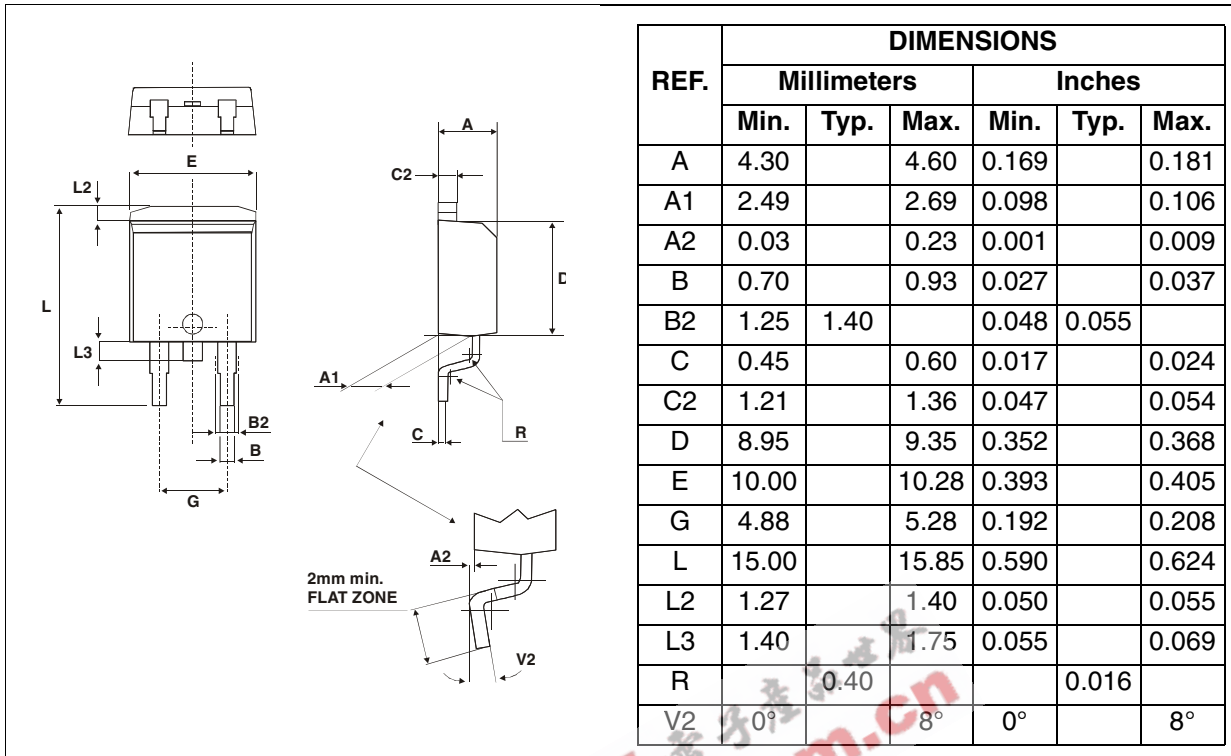
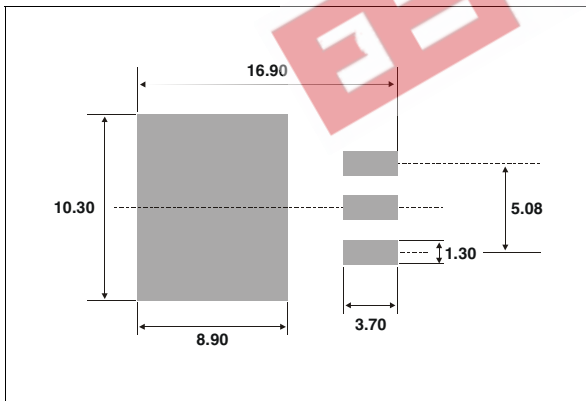


Figure 15: D²PAK Foot Print Dimensions (in millimeters)



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Figure 16: TO-220AB Package Mechanical Data

REF.	DIMENSIONS					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	15.20		15.90	0.598		0.625
a1		3.75			0.147	
a2	13.00		14.00	0.511		0.551
B	10.00		10.40	0.393		0.409
b1	0.61		0.88	0.024		0.034
b2	1.23		1.32	0.048		0.051
C	4.40		4.60	0.173		0.181
c1	0.49		0.70	0.019		0.027
c2	2.40		2.72	0.094		0.107
e	2.40		2.70	0.094		0.106
F	6.20		6.60	0.244		0.259
ØI	3.75		3.85	0.147		0.151
I4	15.80	16.40	16.80	0.622	0.646	0.661
L	2.65		2.95	0.104		0.116
I2	1.14		1.70	0.044		0.066
I3	1.14		1.70	0.044		0.066
M		2.60			0.102	

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.

Table 8: Ordering Information

Ordering type	Marking	Package	Weight	Base qty	Delivery mode
BTA/BTB16-xyzRG	BTA/BTB16xyz	TO-220AB	2.3 g	50	Tube
T1635-xxG	T1635xxG	D ² PAK	1.5 g	50	Tube
T1635-xxG-TR	T1635xxG			1000	Tape & reel

Note: xxx = voltage, yy = sensitivity, z = type

Table 9: Revision History

Date	Revision	Description of Changes
Oct-2002	6A	Last update.
13-Feb-2006	7	TO-220AB delivery mode changed from bulk to tube. ECOPACK statement added.

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